Raising the LUMO level of fullerene derivatives alleviates the

output voltage loss in tin halide perovskite solar cells

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Synthesis method

Chemicals: All of the solvents and chemicals were used as received unless specially stated.



C₆₀-MP synthesis: C₆₀ (0.432 g, 0.6 mmol) and 2 eq. of (2-ethylhexyl)glycine, 1 eq. of 2,3-dimethoxybenzaldehyde were dissolved in 60 mL of 1,2-dichlorobenzene (1,2-DCB). The mixture was heated at 120 °C for 2 h with intense stirring. After cooled down, the organic layer was collected and evaporated under reduced pressure. The crude product was purified through column chromatography (petroleum ether/ethyl acetate = 3/1 vol/vol) to obtain C60-MP (0.188 g; yield: 31.1%) as a brown solid. ¹H NMR (600 MHz, Chloroform-d) δ 7.65 -7.58 (m, 1H), 7.13 (t, *J* = 8.1 Hz, 1H), 6.86 (dt, *J* = 8.2, 1.7 Hz, 1H), 5.60 (d, *J* = 5.4 Hz, 1H), 5.06 (dd, *J* = 9.3, 3.8 Hz, 1H), 4.06 (dd, *J* = 9.3, 5.8 Hz, 1H), 3.87 (d, *J* = 8.6 Hz, 6H), 2.89 (td, *J* = 11.4, 3.0 Hz, 1H), 2.44 (td, *J* = 11.8, 3.2 Hz, 1H), 2.04 -1.91 (m, 2H), 1.62 -1.40 (m, 7H), 1.03 - 0.85 (m, 6H). HR-MS: (ESI) m/z: C₇₈H₂₉NO₂; calculate: 1011.2198; found: 1011.2182.



Fig. S1. ¹H-NMR spectrum of C₆₀-MP recorded in chloroform.



Fig. S2. ¹³C-NMR spectrum of C_{60} -MP recorded in chloroform.



Fig. S3. HR-MS of C₆₀-MP.



C₆₀-**ETPA synthesis**: C₆₀ (0.366 g, 0.5 mmol) and 2 eq. of (2-ethylhexyl)glycine, 1 eq. of 4-(bis(4-methoxyphenyl)amino)benzaldehyde were dissolved in 60 mL of 1,2-DCB. The mixture was heated at 120 °C for 2 h with intense stirring. After cooled down and the solution was removed by rotary evaporator under reduced pressure. The crude product was purified through column chromatography (petroleum ether/ethyl acetate = 9/1 vol/vol) to obtain C₆₀-ETPA (0.174 g; yield: 29.5%) as a brown solid. ¹H NMR (400 MHz, Chloroform-d) δ 7.74 -7.03 (m, 6H), 6.96 (d, *J* = 8.2 Hz, 2H), 6.81 (d, *J* = 8.5 Hz, 4H), 5.14 - 4.90 (m, 2H), 4.06 (d, *J* = 9.4 Hz, 1H), 3.80 (s, 6H), 3.10 (t, *J* = 11.5 Hz, 1H), 2.52 (t, *J* = 9.9 Hz, 1H), 2.20 - 1.89 (m, 2H), 1.46 (s, 6H), 1.13 - 0.98 (m, 6H). HR-MS: (ESI) m/z: C₉₀H₃₈N₂O₂; calculate: 1178.2766; found: 1178.2933.



Fig. S4. ¹H-NMR spectrum of C₆₀-ETPA recorded in chloroform.



Fig. S5. ¹³C-NMR spectrum of C_{60} -ETPA recorded in chloroform.



Fig. S6. HR-MS of C₆₀-ETPA.

Device preparation

The substrates were washed by sonication in deionized water, acetone and ethanol for 20 mins, respectively. After that, the ITO substrates were exposed in UV ozone for 15 mins. The PEDOT:PSS solution was coated on ITO substrates at 4000 rpm for 50 s and annealed at 140 °C for 20 mins. After that, 1.00 M perovskite solution was prepared by mixing FAI, MABr, SnI₂, and SnF₂ in the molar concentrations of 0.75: 0.25: 1: 0.10 with 10 mol% 2-phenylethanamine iodide (PEAI). The solution volume ratio of DMF and DMSO is 4: 1. After stirring 12h, the perovskite precursor solution spread onto the substrate and spin-coated at 8000 rpm for 60s, 150 µL CB anti-solvent was injected onto the film in the last 48 s, and then annealed at 80 °C for 10 mins. After cooling down to room temperature, 55 µL C₆₀-MP and C₆₀-ETPA solution (20 mg mL⁻¹ in Chlorobenzene) was deposited on the perovskite film by spin-coated at 2000 rpm for 30 s and annealed at 70 °C for 10 mins. Finally, 100 nm Ag electrode was deposited under a high vacuum system (< 4 × 10⁻⁶ Pa).

Measurement

UV-vis absorption spectra were measured by UV-2600 (Shimadzu). Cyclic voltammetry (CV) was tested in CHCl₃ with 0.1 M TBAPF₆ with a CHI-660E electrochemical workstation. The tested values were calculated according to the formula of E_{LUMO} = -e(E_{red}^{onset+} 4.8). Photocurrent-voltage (*J-V*) curves were measured by a Keithley 2400 source-measure unit under standard AM 1.5G (100 mW cm⁻²) illumination using a sunlight simulator (San-EI Electric) in the air. All the devices were masked with an aperture area of 0.096 cm². EQE spectra were measured by the quantum efficiency testing and analysis system QE-R (Enlitech). The steady photoluminescence (PL) and time-resolved photoluminescence (TRPL) spectroscopy were measured by using fluorescence lifetime and steady state spectrometer Fluo Time 300 (PicoQuant) with a excitation wavelength at 465 nm laser. The Photo-CELIV, impedance spectroscopy, transient photovoltage (TPV) and Mott-Schottky curve (M-S) information were detected by Piaos system (FLUXiM) with a light intensity of 60 mW

LED. Electron mobility (μ_e) was measured by the Photo-CELIV, the data was calculated by the following equation:

$$\mu_{\rm e} = \frac{2d^2}{3At_{\rm max}^2 [1 + 0.36 \ \triangle j/_{j(0)}]} \quad \text{if } \Delta j < j(0) \tag{1}$$



Fig. S7. EQE spectrum of PC₆₁BM based device.



Fig. S8. Statistic data of $J_{sc}(a)$, FF (b) and PCE (c) with ETMs C₆₀-MP, C₆₀-ETPA and PC₆₁BM.



Fig. S9. Stability data of $PC_{61}BM$ and C_{60} -ETPA based PSCs in N_2 condition, (a) Normalized PCE, (b) Normalized V_{oc} .



Fig. S10. water contact angle of perovskite (a), $PC_{61}BM$ (b), C_{60} -MP (c) and C_{60} -ETPA (d) film.

ETM	$\lambda_{ m edge}$ (nm)	<i>E</i> ₀₋₀ (eV)	HOMO (eV)	LUMO (eV)	Electron mobility (cm ² V ⁻¹ s ⁻¹)	Conductivity (S cm ⁻²)
PC ₆₁ BM	717	1.73	-5.85	-4.12	3.60×10 ⁻⁵	5.17×10 ⁻⁶
C ₆₀ -MP	740	1.68	-5.75	-4.07	5.23×10 ⁻⁵	9.34×10 ⁻⁶
C ₆₀ -ETPA	728	1.70	-5.74	-4.04	4.66×10 ⁻⁵	7.93×10 ⁻⁶

Table S1. The photoelectric and electrochemical properties of C_{60} -MP, C_{60} -ETPA and $PC_{61}BM$.

Table S2. The device performances of TPSCs with PC₆₁BM, C₆₀-MP and C₆₀-ETPA.

ETM	$V_{\rm oc}/{ m V}$	$J_{\rm sc}/{ m mA~cm^{-2}}$	FF/%		PCE/%	
PC ₆₁ BM	0.63	19.34	67.2	6	8.25	
	(0.60 ± 0.03)	(19.90 ± 0.54)	(63.17 ± 4.13)		(7.59 ± 0.36)	
C ₆₀ -MP -	0.69	20.51	66.46		9.43	
	(0.67 ± 0.03)	(20.31 ± 0.34)	(65.31 ± 3.18)		(8.91 ± 0.51)	
C ₆₀ -ETPA	0.76	19.94	67.21		10.17	
	(0.77 ± 0.02)	(19.67 ± 0.94)	(63.69 ± 3.63)		(9.66 ± 0.51)	
ETM	$\tau_1(ns)$	A ₁ (%)	$\tau_2(ns)$	A ₂ (%	b) $\tau_{avg}(ns)$	
PVSK	5.40	63.12	11.44	36.88	8 8.74	
PVSK /PC ₆₁ F	BM 1.85	42.09	4.77	57.91	4.13	
PVSK /C ₆₀ -N	AP 1.48	97.31	2.95	2.69	1.56	
PVSK /C ₆₀ ETPA	- 1.71	66.18	3.26	33.82	2.47	

 Table S3. Summary of TRPL parameters of different layers.